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Set	Items	Description
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S1	5901240	S PRESSURE? OR PIEZO? OR PEIZO?
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S2	2952994	S SENSOR? OR TRANSMITTER? OR TRANSMITTING?
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S3	1234441	S HOUSING OR CASING OR ENCASING OR ENCLOSURE?
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S4	204887	S DIAPHRAGM?
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S5	4082414	S FLUID?
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S6	57652	S MICRO()MECHANICAL? OR MICROMECHANICAL?
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S7	9048021	S CAVITY OR CAVITIES OR OPENING? OR HOLE? ? OR GAP? ? OR CHANNEL? OR CONDUIT? OR PATH? ?
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S8	12586	S MICROREACT? OR MICRO()REACT?
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S9	131171	S S1(2N)S2
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S10	32	S S9 AND S3 AND S6
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S11	14	S S10 AND (S7 OR S4)
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S12	13	RD (unique items)
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S13	9977	S S9 AND S4
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S14	209	S S6 AND S13
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S15	7	S S5 AND S14
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S16	7	S S15 NOT S12
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S17	6	RD (unique items)
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S18	113503	S S7(4N)S5
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S19	33934	S S18 AND S1
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S20	39	S S19 AND S6
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S21	6	S S20 AND S4
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S22	4	RD (unique items)
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? show files

[File 2] **INSPEC** 1898-2006/Mar W4

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[File 6] **NTIS** 1964-2006/Mar W4

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[File 8] **Ei Compendex(R)** 1970-2006/Mar W4

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[File 25] **Weldasearch** 19662006/Mar

(c) 2006 TWI Ltd. All rights reserved.

[File 34] **SciSearch(R) Cited Ref Sci** 1990-2006/Mar W4

(c) 2006 Inst for Sci Info. All rights reserved.

[File 36] **MetalBase** 1965-20060403

(c) 2006 The Dialog Corporation. All rights reserved.

[File 65] **Inside Conferences** 1993-2006/Apr 04

(c) 2006 BLDSC all rts. reserv. All rights reserved.

[File 92] **IHS Intl.Stds.& Specs.** 1999/Nov

(c) 1999 Information Handling Services. All rights reserved.

[File 94] **JICST-EPlus** 1985-2006/Jan W2  
(c)2006 Japan Science and Tech Corp(JST). All rights reserved.

[File 95] **TEME-Technology & Management** 1989-2006/Apr W1  
(c) 2006 FIZ TECHNIK. All rights reserved.

[File 99] **Wilson Appl. Sci & Tech Abs** 1983-2006/Mar  
(c) 2006 The HW Wilson Co. All rights reserved.

[File 103] **Energy SciTec** 1974-2006/Mar B2  
(c) 2006 Contains copyrighted material. All rights reserved.  
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[File 104] **AeroBase** 1999-2006/Mar  
(c) 2006 Contains copyrighted material. All rights reserved.

[File 144] **Pascal** 1973-2006/Mar W2  
(c) 2006 INIST/CNRS. All rights reserved.

[File 239] **Mathsci** 1940-2006/May  
(c) 2006 American Mathematical Society. All rights reserved.

[File 434] **SciSearch(R) Cited Ref Sci** 1974-1989/Dec  
(c) 1998 Inst for Sci Info. All rights reserved.

[File 647] **CMP Computer Fulltext** 1988-2006/Apr W4  
(c) 2006 CMP Media, LLC. All rights reserved.

[File 315] **ChemEng & Biotec Abs** 1970-2006/Mar  
(c) 2006 DECHEMA. All rights reserved.

[File 347] **JAPIO** Dec 1976-2005/Dec(Updated 060404)  
(c) 2006 JPO & JAPIO. All rights reserved.

[File 350] **Derwent WPIX** 1963-2006/UD,UM &UP=200622  
(c) 2006 Thomson Derwent. All rights reserved.  
*\*File 350: For more current information, include File 331 in your search. Enter HELP NEWS 331 for details.*

[File 31] **World Surface Coatings Abs** 1976-2006/Apr  
(c) 2006 PRA Coat. Tech. Cen. All rights reserved.

[File 248] **PIRA** 1975-2006/Mar W2  
(c) 2006 Pira International. All rights reserved.

[File 23] **CSA Technology Research Database** 1963-2006/Mar  
(c) 2006 CSA. All rights reserved.

[File 46] **Corrosion Abstracts** 1966-2006/Mar

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[File 68] **Solid State & Superconductivity Abstracts** 1966-2006/Mar

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[File 60] **ANTE: Abstracts in New Tech & Engineer** 1966-2006/Mar

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[File 33] **Aluminium Industry Abstracts** 1966-2006/Mar

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[File 335] **Ceramic Abstracts/World Ceramics Abstracts** 1966-2006/Mar

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[File 294] **ONTAP(R) SciSearch(R) Cited Ref Science**

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[File 954] **Ei EnCompassLit(TM)** 1965-2006/Apr W1

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[File 953] **Ei EnCompassPat(TM)** 1964-200613

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*\*File 953: Alert feature enhanced for multiple files, duplicate removal, customized scheduling. See HELP ALERT.*

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10/9/1 (Item 1 from file: 350) Links

Derwent WPIX

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015953677      \*\*Image available\*\*

WPI Acc No: 2004-111518/200412

XPX Acc No: N04-088805

**Micromechanical pressure transducer has isolating membrane  
as region of thinner wall joined on one side to membrane type  
pressure sensor and exposed on other side to fluid with  
pressure to be measured**

Patent Assignee: FIRST SENSOR TECHNOLOGY GMBH (FIRS-N); SIEMENS AG (SIEI )

Inventor: **KRAUSE P; STECKENBORN A**; KRAUSSE P

Number of Countries: 031    Number of Patents: 002

Patent Family:

Patent No	Kind	Date	Applicat No	Kind	Date	Week
EP 1382952	A1	20040121	EP 200390196	A	20030702	200412 B
DE 10232721	A1	20040212	DE 1032721	A	20020716	200413

Priority Applications (No Type Date): DE 1032721 A 20020716

Patent Details:

Patent No	Kind	Lan	Pg	Main IPC	Filing Notes
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EP 1382952	A1	G	8	G01L-009/00	
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Designated States (Regional): AL AT BE BG CH CY CZ DE DK EE ES FI FR GB

GR HU IE IT LI LT LU LV MC MK NL PT RO SE SI SK TR

DE 10232721	A1			G01L-009/02	
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Abstract (Basic): EP 1382952 A1

NOVELTY - The device has a micromechanical **housing** (11) with a cavity (16) for a fluid whose pressure is to be measured to which a membrane type **pressure sensor** (12) is attached in micromechanical structural manner. An isolating membrane (22) in the **housing** is formed as a region of thinner wall joined on one side to the **pressure sensor** and exposed on its other side to the fluid with the pressure to be measured.

USE - For pressure sensing.

ADVANTAGE - Simple manufacture and operation.

DESCRIPTION OF DRAWING(S) - The drawing shows a schematic representation of an inventive micromechanical **pressure** transducer with a **sensor** mounted using flip-chip technology

**housing** (11)

cavity (16)

membrane type **pressure sensor** (12)

isolating membrane (22)

base substrate (13)

pp; 8 DwgNo 1/2

Title Terms: PRESSURE; TRANSDUCER; ISOLATE; MEMBRANE; REGION; THINNER; WALL ; JOIN; ONE; SIDE; MEMBRANE; TYPE; PRESSURE; SENSE; EXPOSE; SIDE; FLUID; PRESSURE; MEASURE

Derwent Class: S02; U12; V06

International Patent Class (Main): G01L-009/00; G01L-009/02

File Segment: EPI

Manual Codes (EPI/S-X): S02-F04B; U12-B03F1A; V06-L03

20/9/5 (Item 1 from file: 350) Links

Derwent WPIX

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017532999 \*\*Image available\*\*

WPI Acc No: 2006-044239/200605

XRAM Acc No: C06-016765

XPX Acc No: N06-037822

**Display apparatus for providing immersive input display in  
monocular encasing, has display sharing optical path with eyecup,  
monocular, housing the display, and shutter sharing optical path  
with display and opens upon deformation of eyecup**

Patent Assignee: BURNETT K (BURN-I); DURBIN J (DURB-I); SCHUETTE L (SCHU-I)  
; TREMPER D (TREM-I)

Inventor: BURNETT K; DURBIN J; SCHUETTE L; TREMPER D

Number of Countries: 001 Number of Patents: 001

Patent Family:

Patent No	Kind	Date	Applicat No	Kind	Date	Week
US 20050270251	A1	20051208	US 2004863847	A	20040603	200605 B

Priority Applications (No Type Date): US 2004863847 A 20040603

Patent Details:

Patent No	Kind	Lan	Pg	Main IPC	Filing Notes
US 20050270251	A1		12	G09G-005/00	

Abstract (Basic): US 20050270251 A1

NOVELTY - A display apparatus comprises a deformable eyecup; a display sharing an optical path with the eyecup; a monocular **housing** the display; and a shutter sharing the optical path with the eyecup and the display, where the shutter opens upon deformation of the eyecup.

USE - The apparatus is used for providing an immersive input display in a monocular **encasing**. The monocular can be connected to a system with a video graphics array, National Television System Committee, or equivalent output. The monocular can be applied to fire and rescue as well as police activities, where environmental awareness as well as access to computer data is useful. The monocular is also used to display the situational awareness software used by many emergency agencies while not revealing the user's presence in the immediate surroundings or removing the user's awareness of the immediate surroundings.

ADVANTAGE - The apparatus minimizes or eliminates light emission from the display, as well as inhibits or prevents ambient light from affecting visibility of the display.

DESCRIPTION OF DRAWING(S) - The figure is a block diagram of a display apparatus.

pp; 12 DwgNo 1/7

Technology Focus:

TECHNOLOGY FOCUS - ELECTRONICS - Preferred Component: The shutter comprises a mechanical iris, a liquid crystal shutter, a **micro-mechanical** micro-shutter array, and/or a shutter comprising flaps that flex upon the deformation. The apparatus further comprises a

**pressure sensor** communicating with eyecup and the shutter such that the deformation electrically actuates the iris. The display comprises a micro-display comprising an organic light emitting display, a liquid crystal on silicon display, a transmissive display, a transreflective display, a reflective display, a plasma display, a digital light processing display, and/or a scanned-beam display. The apparatus further comprises a lens sharing the optical path with the shutter and the display. The apparatus further comprises at least one of a focus slide and a focus ring for adjusting a distance between the lens and the display; a wireless receiver for receiving display data and sending the display data to the display; one of a wired connection and a wireless transceiver for receiving display data and sending the display data to the display; and at least one of a pointer controller, a scroll wheel, a touch pad, a mouse button, and a keypad for controlling the display data.

POLYMERS - Preferred Component: The eyecup comprises rubber, neoprene, plastic, and/or pleated material

Title Terms: DISPLAY; APPARATUS; INPUT; DISPLAY; MONOCULAR; ENCASED; DISPLAY; SHARE; OPTICAL; PATH; MONOCULAR; **HOUSING**; DISPLAY; SHUTTER; SHARE; OPTICAL; PATH; DISPLAY; **OPEN**; DEFORM

Derwent Class: A97; P85; S02; T04; W03; W05; W07

International Patent Class (Main): G09G-005/00

File Segment: CPI; EPI; EngPI

Manual Codes (CPI/A-N): A12-E11; A12-L03

Manual Codes (EPI/S-X): S02-F04B; T04-H03C9; W03-A09A; W03-A18A; W05-E07; W07-G

Polymer Indexing (PS):

- \*001\* 2004; R01079 G0828 G0817 D01 D12 D10 D51 D54 D56 D58 D69 D84 C1 7A; H0000; P0328 ; P0340
- \*002\* 2004; H0124-R
- \*003\* 2004; Q9999 Q8264-R; ND01; K9416; Q9999 Q7512-R; K9905; Q9999 Q9029

20/9/7 (Item 3 from file: 350) Links

Derwent WPIX

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017220692      \*\*Image available\*\*

WPI Acc No: 2005-544310/200556

XRAM Acc No: C05-164905

XRPX Acc No: N05-445989

**Wrapping of semiconductor pastilles to form structures for  
micromechanical devices incorporating a membrane, notably for  
pressure sensors**

Patent Assignee: BOSCH GMBH ROBERT (BOSC ); BENZEL H (BENZ-I); GUENSCHER R  
(GUEN-I); HAAG F (HAAG-I); PINTER S (PINT-I); WEIBLEN K (WEIB-I)

Inventor: BENZEL H; GUENSCHER R; HAAG F; PINTER S; WEIBLEN K; GUNSCHER R;  
HARK F

Number of Countries: 004    Number of Patents: 004

Patent Family:

Patent No	Kind	Date	Applicat No	Kind	Date	Week
FR 2865575	A1	20050729	FR 200550168	A	20050120	200556 B
US 20050186703	A1	20050825	US 200541157	A	20050121	200556
DE 102004003413	A1	20050811	DE 102004003413	A	20040123	200556
JP 2005210131	A	20050804	JP 200515924	A	20050124	200556

Priority Applications (No Type Date): DE 102004003413 A 20040123

Patent Details:

Patent No	Kind	Lan	Pg	Main IPC	Filing Notes
FR 2865575	A1	32		H01L-021/56	
US 20050186703	A1			H01L-021/50	
DE 102004003413	A1			H01L-021/52	
JP 2005210131	A	16		H01L-023/02	

Abstract (Basic): FR 2865575 A1

NOVELTY - Wrapping of semiconductor pastilles comprises:

- (a) production of a semiconductor pastille (5) with a first membrane zone (55);
- (b) installation of a cover (10) above the membrane zone leaving behind the membrane zone;
- (c) installation of the semiconductor pastille on a mounting frame (1);
- (d) realisation of a moulded **casing** (20) around the semiconductor pastille and of at least one partial zone of the mounting frame in order to wrap the semiconductor pastille.

DETAILED DESCRIPTION - An INDEPENDENT CLAIM is also included for a semiconductor pastille produced.

USE - For wrapping a semiconductor pastille to form a semiconductor pastille structure for a **micromechanical** device incorporating a **pressure sensor**.

ADVANTAGE - The invention allows moulding or injection around the semiconductor pastille with a membrane zone to form a **casing** similar to that used for integrated circuits, which are simple and economic to fabricate. The cover above the membrane zone also mechanically reinforces the membrane zone whilst protecting against the



moulded mass. Since the cover is of silicon it has the same dilation coefficient as the semiconductor pastille which leads to a lower temperature effect in the output signal. It also eliminates the need for a passivation gel on the membrane thus providing a lower transverse sensitivity with respect to accelerations and more significant application pressures.

DESCRIPTION OF DRAWING(S) - The figure shows the wrapping of a semiconductor pastille according to the invention and shows a cross-sectional view of the corresponding semiconductor pastille structure.

Mounting frame; (1)  
Mounting frame passage; (2)  
Semiconductor pastille; (5)  
Cover; (10)  
Glass sealing layer; (11)  
Moulded **casing**; (20)  
Passage; (21)  
Piezoelectric resistances; (51)  
Integrated circuit; (52)  
Liaison strap; (53)  
Membrane; (55)  
**Cavity**; (58)  
Lateral zone of pastille; (59)  
Liaison wire; (60)  
**Cavity**; (65)  
Soldering layer; (70)  
Glass base; (140)  
Piercing. (141)  
pp; 32 DwgNo 1/9

Technology Focus:

TECHNOLOGY FOCUS - CERAMICS AND GLASS - The cover is preferably made of silicon to provide the same dilation coefficient as that of the semiconductor pastille.

Title Terms: WRAP; SEMICONDUCTOR; PASTILLE; FORM; STRUCTURE; DEVICE;  
INCORPORATE; MEMBRANE; NOTABLY; PRESSURE; SENSE

Derwent Class: L03; Q68; S02; U11; U12

International Patent Class (Main): H01L-021/50; H01L-021/52; H01L-021/56;  
H01L-023/02

International Patent Class (Additional): B81B-003/00; B81C-001/00;  
B81C-003/00; G01L-009/00; H01L-021/60

File Segment: CPI; EPI; EngPI

Manual Codes (CPI/A-N): L04-C21; L04-E10

Manual Codes (EPI/S-X): S02-F04B3; U11-C18C; U12-B03E; U12-B03F1

20/9/8 (Item 4 from file: 350) Links

Derwent WPIX

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017162285      \*\*Image available\*\*

WPI Acc No: 2005-486631/200549

XPX Acc No: N05-396103

**Micromechanical component manufacturing method e.g.**

**for micromechanical sensor, involves applying printed conductor to walls of cavity on substrate back**

Patent Assignee: BOSCH GMBH ROBERT (BOSC ); BENZEL H (BENZ-I); FINKBEINER S (FINK-I); GONSKA J (GONS-I); SCHELLING C (SCHE-I)

Inventor: BENZEL H; FINKBEINER S; GONSKA J; SCHELLING C

Number of Countries: 002    Number of Patents: 002

Patent Family:

Patent No	Kind	Date	Applicat No	Kind	Date	Week
US 20050133880	A1	20050623	US 200416617	A	20041217	200549 B
DE 10359217	A1	20050728	DE 10359217	A	20031217	200549

Priority Applications (No Type Date): DE 10359217 A 20031217

Patent Details:

Patent No	Kind	Lan	Pg	Main IPC	Filing Notes
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US 20050133880	A1		9	G02B-026/00	
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DE 10359217	A1			B81B-003/00	
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Abstract (Basic): US 20050133880 A1

NOVELTY - A printed conductor (120) is applied to the walls of a **cavity** (140) on the substrate back (160), after forming an insulation layer (200). A printed conductor (110) is applied onto substrate front (150). A circuit element (220) formed at the substrate front is electrically connected to the printed conductor at substrate back by through-plating (130).

DETAILED DESCRIPTION - An INDEPENDENT CLAIM is also included for **micromechanical** component.

USE - For manufacturing **micromechanical** component (claimed) e.g. **micromechanical** sensor including manifold **sensor** element like **pressure sensor**, air mass **sensor**, acceleration sensor, yaw rate sensor in integrated sensor system.

ADVANTAGE - The **micromechanical** components can be easily arranged inside a **housing**, since there is no complex wiring from one side of the component to the other side.

DESCRIPTION OF DRAWING(S) - The figure depicts a cross-sectional view explaining **micromechanical** component manufacture.

substrate (100)  
printed conductors (110,120)  
through-plating (130)  
**cavity** (140)  
substrate front (150)  
substrate back (160)  
insulation layer (200)  
circuit element (220)  
pp; 9 DwgNo 2/5

Technology Focus:

TECHNOLOGY FOCUS - INORGANIC CHEMISTRY - The printed conductor is electrically insulated from the substrate by the insulation layer containing silicon oxide (SiOx) or silicon nitride.

ORGANIC CHEMISTRY - The printed conductor is electrically insulated from the substrate by the insulation layer containing silicon oxide (SiOx) or silicon nitride.

Title Terms: COMPONENT; MANUFACTURE; METHOD; SENSE; APPLY; PRINT; CONDUCTOR  
; WALL; **CAVITY**; SUBSTRATE; BACK

Derwent Class: P81; Q68; S02; U12; V06

International Patent Class (Main): B81B-003/00; G02B-026/00

International Patent Class (Additional): B81C-001/00

File Segment: EPI; EngPI

Manual Codes (EPI/S-X): S02-C01F1; S02-F04B3; S02-G03; U12-B03E; U12-B03F1A  
; V06-L02A; V06-L03

20/9/9 (Item 5 from file: 350) Links

Derwent WPIX

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016963041      \*\*Image available\*\*

WPI Acc No: 2005-287353/200530

XRAM Acc No: C05-089447

XRPX Acc No: N05-235451

**Fabrication of a micro-mechanical sensor**

**incorporating a sensor element and a working circuit for a wide range of data acquisition applications**

Patent Assignee: BOSCH GMBH ROBERT (BOSC ); BENZEL H (BENZ-I); SCHAEFER F (SCHA-I); SCHELLING C (SCHE-I)

Inventor: BENZEL H; SCHAEFER F; SCHELLING C

Number of Countries: 003    Number of Patents: 003

Patent Family:

Patent No	Kind	Date	Applicat No	Kind	Date	Week
FR 2860779	A1	20050415	FR 200452287	A	20041007	200530 B
DE 10347215	A1	20050512	DE 10347215	A	20031010	200532
US 20050115321	A1	20050602	US 2004958014	A	20041004	200537

Priority Applications (No Type Date): DE 10347215 A 20031010

Patent Details:

Patent No	Kind	Lan	Pg	Main IPC	Filing	Notes
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FR 2860779	A1		19	B81C-001/00		
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DE 10347215	A1			B81C-001/00		
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US 20050115321	A1			G01N-025/00		
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Abstract (Basic): FR 2860779 A1

NOVELTY - A **micro-mechanical** sensor is fabricated incorporating a component (100) of a first material with at least one sensor zone having a sensor element, a part of a working circuit (130) and first and second sides. The first side incorporates the sensor element and the second side incorporates the working circuit. At least a part of the sensor zone and/or the working circuit are realised by a **micro-mechanical** machining in the first material.

DETAILED DESCRIPTION - An INDEPENDENT CLAIM is also included for the **micro-mechanical** sensor fabricated in this manner..

USE - The invention is used for the fabrication of **micro-mechanical** sensors applicable for the measurement of pressure or temperature or air mass or air quality or dew point or gas humidity or the chemical composition of a gas or liquid or acceleration or speed of rotation or thermal conductivity (all claimed).

ADVANTAGE - The invention allows the fabrication of **micro-mechanical** sensors for a wide range of applications. It provides economic advantages and surface gains in the fabrication of the sensors. Simultaneous treatment of several sides of the component reduce the fabrication time and the spatial separation of the working circuit and the sensor zone leads to a setting economy for the upper surface effectively needed and that will be exposed to the substance to be measured.

DESCRIPTION OF DRAWING(S) - The drawing illustrates a form of

**pressure sensor** according to the invention.

First component; (100)  
Part of working circuit; (130)  
Linkage; (410)  
Conducting track; (450)  
Second component; (500)  
**Casing;** (510)  
**Cavity;** (520)  
Oscillating structure; (530)  
Sensor zone; (540)  
Intermediate layer. (550)  
pp; 19 DwgNo 5/5

**Technology Focus:**

TECHNOLOGY FOCUS - ELECTRONICS - The sensor element may be a membrane or a resistive structure or piezo-sensitive resistance layers or a temperature sensor or an electrode device or an oscillating structure (claimed).

Title Terms: FABRICATE; MICRO; MECHANICAL; SENSE; INCORPORATE; SENSE; ELEMENT; WORK; CIRCUIT; WIDE; RANGE; DATA; ACQUIRE; APPLY

Derwent Class: L03; Q68; S02; S03; U11; U12; V06

International Patent Class (Main): B81C-001/00; G01N-025/00

International Patent Class (Additional): B81B-003/00; B81B-007/00;  
G01K-007/00; G01L-009/00; G01N-007/00; G01P-015/00; H01L-021/461;  
H01L-029/84

File Segment: CPI; EPI; EngPI

Manual Codes (CPI/A-N): L03-G10A; L04-E10

Manual Codes (EPI/S-X): S02-F04B1; S02-F04B2; S03-B01C; S03-E01A; S03-E02X;  
U11-C18C; U12-B03F1A; V06-L02A; V06-L03; V06-L10

12/9/11 (Item 7 from file: 350) Links

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013516966 \*\*Image available\*\*

WPI Acc No: 2001-001172/200101

XRPX Acc No: N01-000963

**Micromechanical or micromechanical-electronic component device - has channel formed in surface of micromechanical of micromechanical-electronic component for isolating outer region attached to casing of device from its inner region**

Patent Assignee: SIEMENS AG (SIEI .)

Inventor: AIGNER R; KAPELS H; MARKSTEINER S; OPPERMANN K

Number of Countries: 025 Number of Patents: 001

Patent Family:

Patent No	Kind	Date	Applicat No	Kind	Date	Week
EP 1055921	A2	20001129	EP 2000109364	A	20000502	200101 B

Priority Applications (No Type Date): DE 1024084 A 19990526

Patent Details:

Patent No	Kind	Lan	Pg	Main IPC	Filing Notes
EP 1055921	A2	G	5	G01L-019/00	

Designated States (Regional): AL AT BE CH CY DE DK ES FI FR GB GR IE IT

LI LT LU LV MC MK NL PT RO SE SI

Abstract (Basic): EP 1055921 A

The device has a **casing** in which at least one

**micromechanical**

or **micromechanical-electronic component (2)** is supported.

The

surface of the component has at least one **channel (3)**

dividing

it into an inner region (22) and an outer region mechanically secured to the **casing**.

The **channel** provides mechanical isolation between the outer region and the inner region, so that deformation of the outer region caused by the **casing** is not transmitted to the inner region.

USE - Device is used as acceleration **sensor** or

**pressure sensor**.

ADVANTAGE -Inner region of **micromechanical** or micromecha.

Dwg.2/3

Title Terms: ELECTRONIC; COMPONENT; DEVICE; **CHANNEL**; FORMING;

SURFACE; ELECTRONIC; COMPONENT; ISOLATE; OUTER; REGION; ATTACH;

**CASING**; DEVICE; INNER; REGION

Derwent Class: S02; U12

International Patent Class (Main): G01L-019/00

File Segment: EPI

Manual Codes (EPI/S-X): S02-F04B3; S02-F04E; S02-G03; U12-B03F

12/9/12 (Item 8 from file: 350) Links  
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013076559      \*\*Image available\*\*  
WPI Acc No: 2000-248431/200022  
XRAM Acc No: C00-075318  
XRPX Acc No: N00-186011

**Semiconductor micromechanical sensor, e.g. a pressure sensor, is fixed in a housing by a gel to provide an elastic, viscous or flexible bond and long term protection**

Patent Assignee: SIEMENS AG (SIEI )  
Inventor: WILDGEN A  
Number of Countries: 003    Number of Patents: 004  
Patent Family:

Patent No	Kind	Date	Applicat No	Kind	Date	Week	
FR 2783048	A1	20000310	FR 9910868	A	19990827	200022	B
DE 19840829	A1	20000323	DE 198040829	A	19980907	200022	
US 6350630	B1	20020226	US 99390166	A	19990907	200220	
DE 19840829	B4	20051020	DE 198040829	A	19980907	200569	

Priority Applications (No Type Date): DE 198040829 A 19980907  
Patent Details:

Patent No	Kind	Lan	Pg	Main IPC	Filing Notes
FR 2783048	A1		14	G01L-019/14	
DE 19840829	A1			G01L-019/14	
US 6350630	B1			H01L-021/48	
DE 19840829	B4			G01L-019/14	

Abstract (Basic): FR 2783048 A1

NOVELTY - Semiconductor **micromechanical** sensor (12) fixed in a **housing** (11) by (a) positioning sensor on a seating surface (112) in a **housing** recess (111); (b) simultaneously forming an electrical connection (14) between the sensor and electrical contact (15) on the **housing** and fixing the sensor to the **housing** by pressure reduction through a **conduit** (114); and (c) filling recess with a fixing gel (13).

DETAILED DESCRIPTION - An INDEPENDENT CLAIM is also included for a sensor structure produced by the above process.

USE - For **housing** a semiconductor **micromechanical** sensor such as a **pressure sensor**.

ADVANTAGE - The gel produces an elastic, viscous or flexible bond between the sensor chip and the **housing** to avoid affecting the sensor characteristics, provides long term protection of the sensor from its environment and avoids the need for use of a support, an adhesive and a protective membrane so that manufacture is simplified and is more economical.

DESCRIPTION OF DRAWING(S) - The drawing shows a sensor structure according to the invention.

**Housing** (11)

Sensor chip (12)

Gel (13)  
Electrical connection (14)  
Electrical contact (15)  
Recess (111)  
Seating surface (112)  
Pressure reduction **conduit** (114)  
pp; 14 DwgNo 1/3

Technology Focus:

TECHNOLOGY FOCUS - POLYMERS - Preferred Gel: The gel is a fluorinated silicone gel.

Title Terms: SEMICONDUCTOR; SENSE; PRESSURE; SENSE; FIX; **HOUSING**;  
GEL; ELASTIC; VISCOSITY; FLEXIBLE; BOND; LONG; TERM; PROTECT

Derwent Class: A88; S02

International Patent Class (Main): G01L-019/14; H01L-021/48

International Patent Class (Additional): H01L-023/02; H01L-029/84

File Segment: CPI; EPI

Manual Codes (CPI/A-N): A06-A00E2; A12-E13

Manual Codes (EPI/S-X): S02-F04E

Polymer Indexing (PS):

- \*001\* 018; F- 7A; S9999 S1365; P1445-R F81 Si 4A; M9999 M2255 M2222
- \*002\* 018; ND01; Q9999 Q7874; B9999 B3930-R B3838 B3747; B9999 B3554-R;  
B9999 B4035 B3930 B3838 B3747; K9483-R; K9676-R
- \*003\* 018; F- 7A; H0157



22/9/4 (Item 2 from file: 350) Links

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011268974 \*\*Image available\*\*

WPI Acc No: 1997-246877/199723

XRPX Acc No: N97-203510

**Micro mechanically manufactured flow**

**restriction system with passage opening - is formed in first main surface of substrate with duct formed in second main surface of substrate in fluid communication with passage opening also with diaphragm**

Patent Assignee: FRAUNHOFER GES FOERDERUNG ANGEWANDTEN (FRAU )

Inventor: WOIAS P

Number of Countries: 020 Number of Patents: 007

Patent Family:

Patent No	Kind	Date	Applicat No	Kind	Date	Week	
DE 29701418	U1	19970430	DE 97U2001418	U	19970128	199723	B
DE 19650116	C1	19980402	DE 1050116	A	19961203	199817	
WO 9825110	A1	19980611	WO 97EP6342	A	19971113	199829	
EP 943076	A1	19990922	EP 97951190	A	19971113	199943	
			WO 97EP6342	A	19971113		
EP 943076	B1	20000510	EP 97951190	A	19971113	200027	
			WO 97EP6342	A	19971113		
DE 59701675	G	20000615	DE 501675	A	19971113	200036	
			EP 97951190	A	19971113		
			WO 97EP6342	A	19971113		
US 6263741	B1	20010724	WO 97EP6342	A	19971113	200146	
			US 99319169	A	19990601		

Priority Applications (No Type Date): DE 1050116 A 19961203

Patent Details:

Patent No	Kind	Lan	Pg	Main IPC	Filing Notes
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DE 29701418	U1	14	G01F-001/40		
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DE 19650116	C1	6	G01F-001/40		
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WO 9825110	A1 G		G01F-001/38		
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Designated States (National): JP US

Designated States (Regional): AT BE CH DE DK ES FI FR GB GR IE IT LU MC

NL PT SE

EP 943076	A1 G		G01F-001/38	Based on patent WO 9825110	
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Designated States (Regional): CH DE DK FR GB IT LI NL SE

EP 943076	B1 G		G01F-001/38	Based on patent WO 9825110	
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Designated States (Regional): CH DE DK FR GB IT LI NL SE

DE 59701675	G		G01F-001/38	Based on patent EP 943076	
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Based on patent WO 9825110

US 6263741	B1		G01F-001/38	Based on patent WO 9825110	
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Abstract (Basic): DE 29701418 U

The system has a passage opening (12) formed in the first main surface of the substrate (10), with a duct (16) formed in a second main surface of the substrate, communicating **fluidly** with the passage opening, also with a **diaphragm** (22). One **diaphragm**

electrode (26) at least is formed on the **diaphragm**. A cover system (30) is applied on the second main surface of the substrate, such that the **diaphragm** electrode together with the duct, define a flow resistance of the flow restriction system.

The cover system has a counter electrode (32) which spaced at a distance from the **diaphragm** electrode, lies opposite the same. In such a manner that the **diaphragm** electrode and the counter electrode define a capacitive **pressure** pick-up. A passage opening is formed in the cover system, which has fluid communication with the duct.

USE/ADVANTAGE - Liquid dosing field. Cost effective and simple **micro mechanically** manufactured flow restriction system, with at least one integrated **pressure** sensor.

Dwg.1/2

Title Terms: MICRO; MECHANICAL; MANUFACTURE; FLOW; RESTRICT; SYSTEM; PASSAGE; OPEN; FORMING; FIRST; MAIN; SURFACE; SUBSTRATE; DUCT; FORMING; SECOND; MAIN; SURFACE; SUBSTRATE; FLUID; COMMUNICATE; PASSAGE; OPEN;  
**DIAPHRAGM**

Derwent Class: Q57; S02

International Patent Class (Main): G01F-001/38; G01F-001/40

International Patent Class (Additional): F15C-005/00; G01F-001/56;

G01L-007/08; G01L-009/12

File Segment: EPI; EngPI

Manual Codes (EPI/S-X): S02-C01A1; S02-C01B4